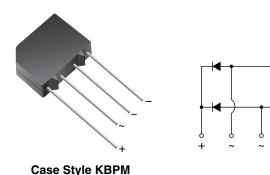


3KBP005M, 3KBP01M, 3KBP02M, 3KBP04M, 3KBP06M, 3KBP08M

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Glass Passivated Single-Phase Bridge Rectifier



| PRIMARY CHARACTERISTICS | | | | | | |
|-------------------------|---|--|--|--|--|--|
| Package | KBPM | | | | | |
| I _{F(AV)} | 3.0 A | | | | | |
| V _{RRM} | 50 V, 100 V, 200 V, 400 V, 600 V, 800 V | | | | | |
| I _{FSM} | 80 A | | | | | |
| I _R | 5 μΑ | | | | | |
| V_F at $I_F = 3.0 A$ | 1.05 V | | | | | |
| T _J max. | 150 °C | | | | | |
| Diode variations | In-Line | | | | | |

FEATURES







· High case dielectric strength

Solder dip 275 °C max. 10 s, per JESD 22-B106

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, and telecommunication applications.

MECHANICAL DATA

Case: KBPM

Molding compound meets UL 94 V-0 flammability rating Base P/N-E4 - RoHS-compliant, commercial grade

Terminals: Silver plated leads, solderable per

J-STD-002 and JESD22-B102 **Polarity:** As marked on body

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | | | |
|---|-----------------------------------|--------------------------------|---------|---------|---------|---------|------------------|------|
| PARAMETER | SYMBOL | 3KBP005M | 3KBP01M | 3КВР02М | 3KBP04M | 3КВР06М | 3КВР08М | UNIT |
| Maximum repetitive peak reverse voltage | V _{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | V |
| Maximum RMS voltage | V _{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | V |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | V |
| Maximum average forward output rectified current at $T_A = 55$ °C (Fig. 1) | I _{F(AV)} | 3.0 | | | | | Α | |
| Peak forward surge current 50 Hz single half sine-wave superimposed on rated load | I _{FSM} | M 80 | | | | | А | |
| Rating for fusing (t < 10 ms) | l ² t | l ² t 32 | | | | | A ² s | |
| Operating junction and storage temperature range | T _J , T _{STG} | T _{STG} - 55 to + 150 | | | | | °C | |

| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | | | |
|---|-------------------------|----------------|----------|---------|---------|---------|---------|---------|------|
| PARAMETER | TEST CONDITIONS | SYMBOL | 3КВР005М | 3KBP01M | 3KBP02M | 3KBP04M | 3КВР06М | 3KBP08M | UNIT |
| Maximum instantaneous forward voltage drop per diode | 3.0 A | V _F | 1.05 | | | | V | | |
| Maximum DC reverse current at rated DC | T _J = 25 °C | 1 | 5.0 | | | | | | |
| blocking voltage per diode | T _J = 125 °C | IR | 500 | | | | | | μΑ |
| Typical junction capacitance per diode | 4.0 V, 1 MHz | CJ | 25 | | | | pF | | |



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| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | | |
|---|-----------------|---|--|--|--|--|--|-------|
| PARAMETER | SYMBOL | MBOL 3KBP005M 3KBP01M 3KBP02M 3KBP04M 3KBP06M 3KBP08M | | | | | | UNIT |
| Typical thermal resistance (1) | $R_{\theta JA}$ | 30 | | | | | | °C/W |
| Typical triefmal resistance (7) | $R_{\theta JL}$ | 11 | | | | | | J/ VV |

Note

⁽¹⁾ Thermal resistance from junction to ambient and from junction to lead mounted on PCB with, 0.47" x 0.47" (12 mm x 12 mm) copper pads

| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|-----------------|--------------|---------------|----------------------|--|--|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | | | |
| 3KBP06M-E4/51 | 1.912 | 51 | 600 | Anti-static PVC tray | | | | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

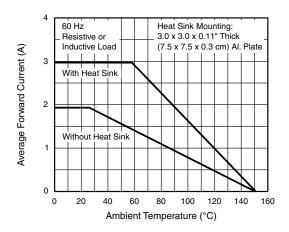


Fig. 1 - Forward Current Derating Curve

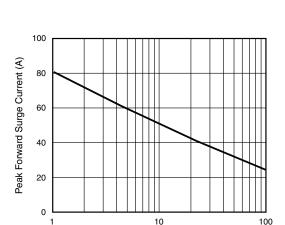


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

Number of Cycles at 60 Hz

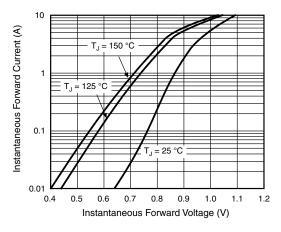


Fig. 3 - Typical Forward Characteristics Per Diode

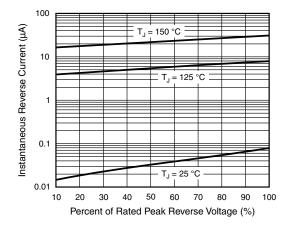


Fig. 4 - Typical Forward Characteristics Per Diode

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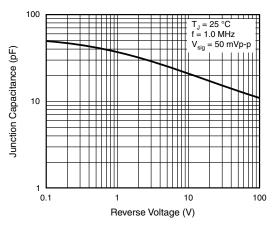
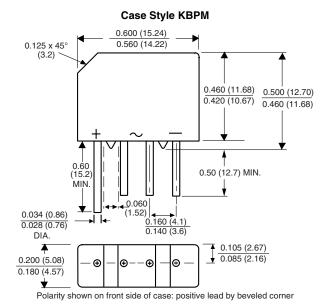


Fig. 5 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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